The background image is a composite of two photographs showing a person wearing blue nitrile gloves working on a piece of scientific equipment. The equipment consists of a metal frame with a circular component that has blue horizontal ridges. The person is using a tool to adjust or mount a small component on this circular surface. The lighting is bright, and the overall scene is a technical, laboratory-like environment.

Sara Gamba, Danaé Valdenaire, Laura Francesca Iacob, Marco Ricci, Daniela Spreng  
Supervisor: Andrei Puiu

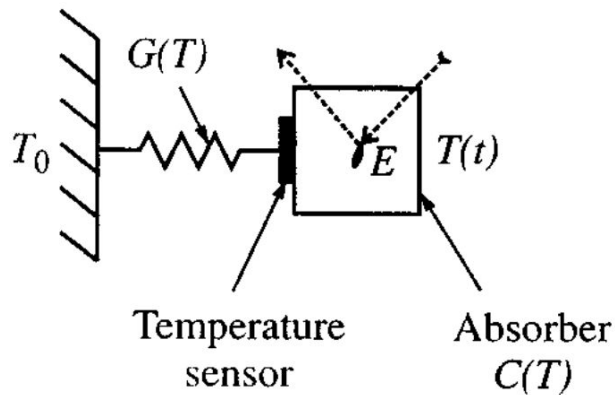
# Hands-on cryogenic calorimeters

Mounting of a scintillating calorimeter with double readout  
~~and subsequent cooldown to 10 mK~~

Gran Sasso Hands-On 2025

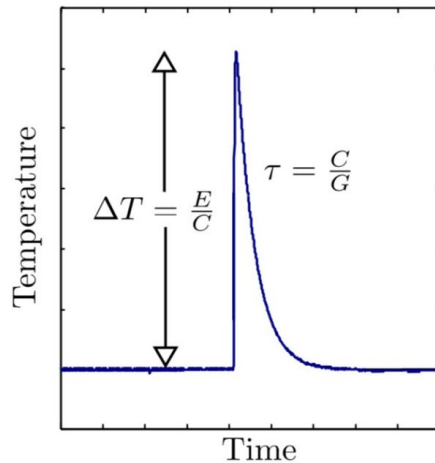
# Cryogenic calorimeters

Low temperature detectors (LTD) are detectors that operate at very low temperatures  $\sim 10$  mK.



When particles interact in the absorber they will deposit an amount of energy  $E$ , creating a temperature variation  $\Delta T \propto E/C(T)$  in the absorber+thermometer system.

Then the system goes back to equilibrium through the conductance  $G(T)$  connected to the thermal bath  $T_0$ .



We want to minimize both decay time  $\tau \propto C/G$  and the resolution  $\sigma_E^2 = k_B T^2 C$ . This means that we want a high thermal conductance  $G(T)$  but a low capacitance  $C(T)$ .

One of the main advantages of LTDs is their very low thresholds, usually  $O(1-10)$  eV.

⚠ **Smaller** detector  $\rightarrow$  **lower C**  $\rightarrow$  better resolution and speed.

# Detectors overview

**Equilibrium detectors** used during the hands-on:

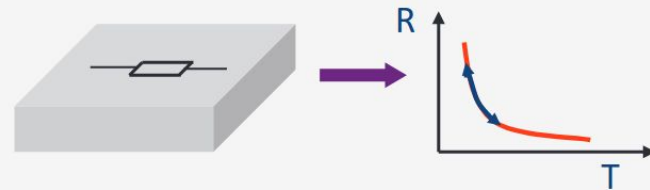
## Neutron Transmutation Doped Thermistors (NTD):

- Neutron-doped germanium crystals;
- **Semiconductor thermistors** with
$$R(T) = R_0 \exp((T/T_0)^{0.5});$$
- **Negative derivative sensor**:  $\Delta R \Delta T < 0$ ;
- High impedance;
- Current bias.

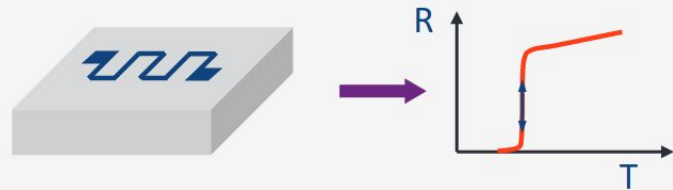
## Transition Edge Sensors (TES):

- Working at the **transition between normal and superconductivity**;
- **Positive derivative sensor**:  $\Delta R \Delta T > 0$ ;
- Voltage bias.

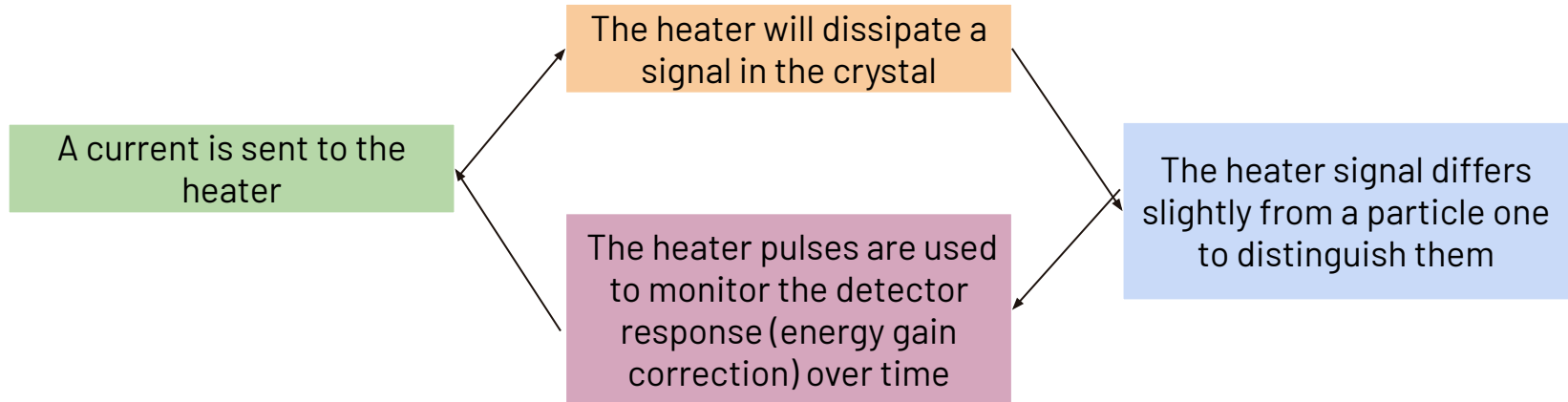
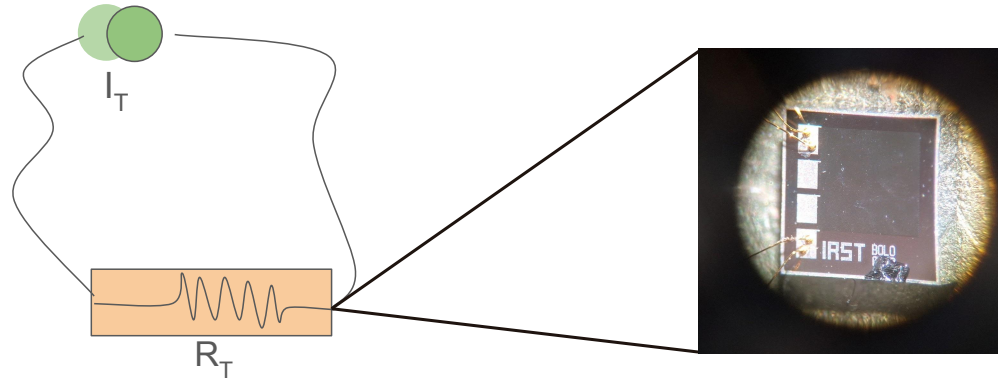
Resistance of highly doped semiconductors



Resistance at superconducting transition, TES



# Heaters to monitor the detector response





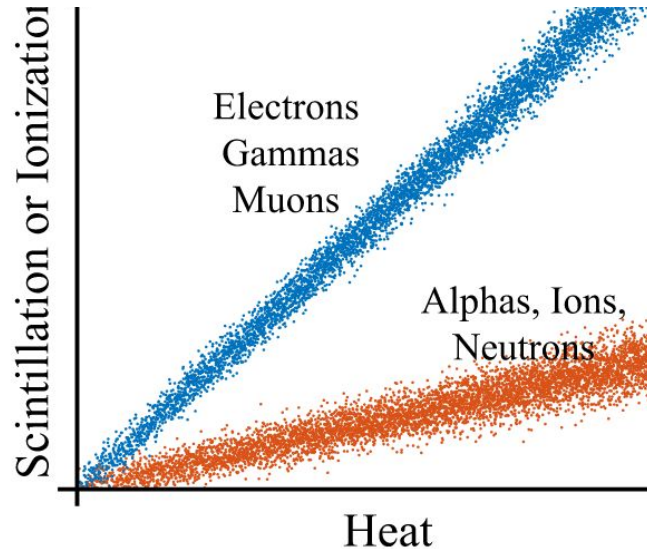
# Double readout for particle ID

## Double readout:

- Channel 1 (LTD): **phonon detector** (A1);
- Channel 2 **scintillation or ionization light** (A2);

The ratio  $A1/A2$  (light yield) depends on the interacting particle → **Particle identification**

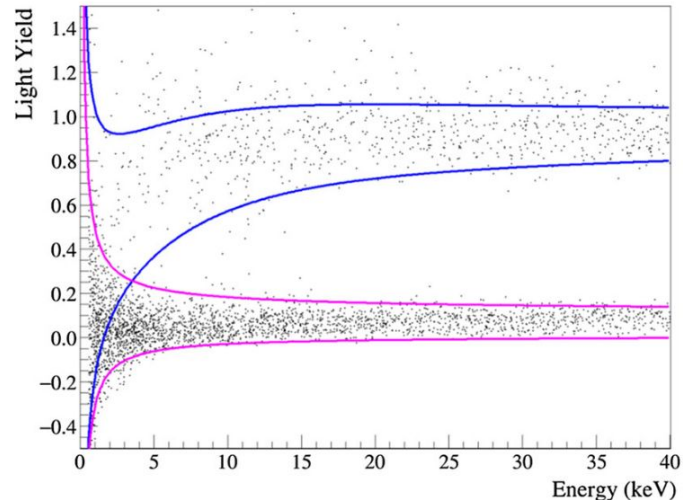
→ Important to distinguish between **nuclear** and **electronic** recoil:



**heat-ionization:** electrons, photons (higher ionization yield) and  $\alpha$ , ions and neutrons;



**heat-scintillation:** recoil electrons - higher light yield, blue - and nuclear recoil - pink.

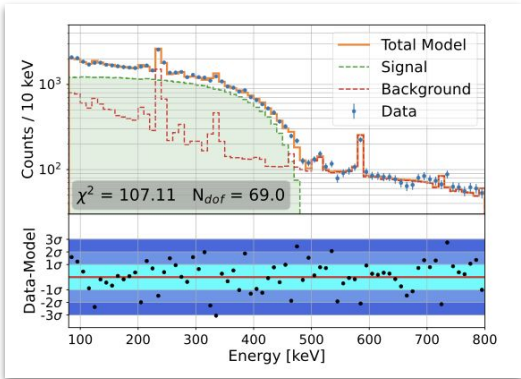


# Crystal absorbers

## Indium Arsenide (InAs)

Measurement of forbidden  $\beta$  decays to investigate axial coupling constant  $g_A$

Measurement of the  $\beta$ -decay spectrum of Indium 115  
→ Low-energy part is used to study  $g_A$



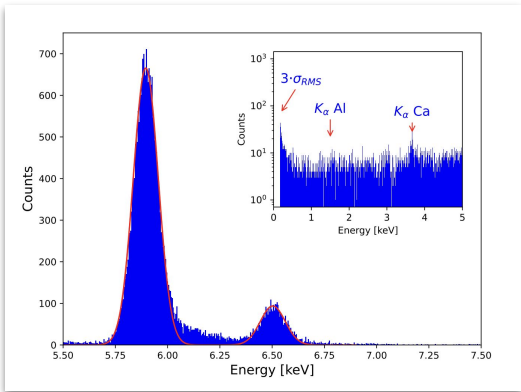
<https://arxiv.org/pdf/2507.07119>

Beta decay spectrum of In 115

## Gallium Arsenide (GaAs)

sub-GeV dark matter search

Threshold as low as possible to increase the sensitivity  
→ 2 NTDs improve the signal to noise ratio



<https://arxiv.org/pdf/2507.07119>

Low energy X-ray spectrum - Mn  $K_\alpha$  peak  
measured with  $\sigma = 1$  eV

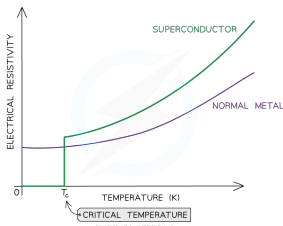
# Hands-on overview

Wire bonding



Gluing of detectors and heaters on crystals

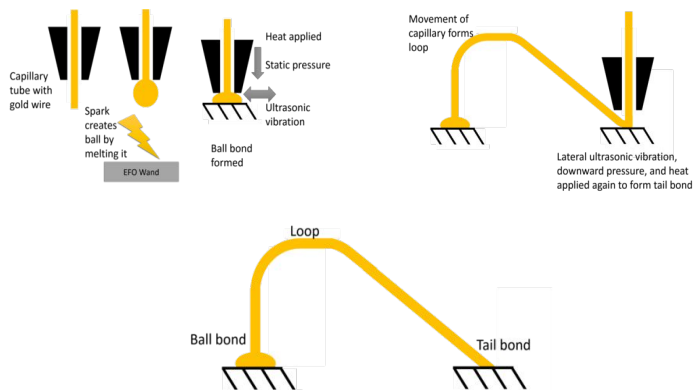
Assembly in the copper frame for future tests at low temperatures



Preparation for measuring the transition temperature of a superconductive film

# Wire bonding: micro-welding technique that uses thin metal wires bonded by means of ultrasonic vibration.

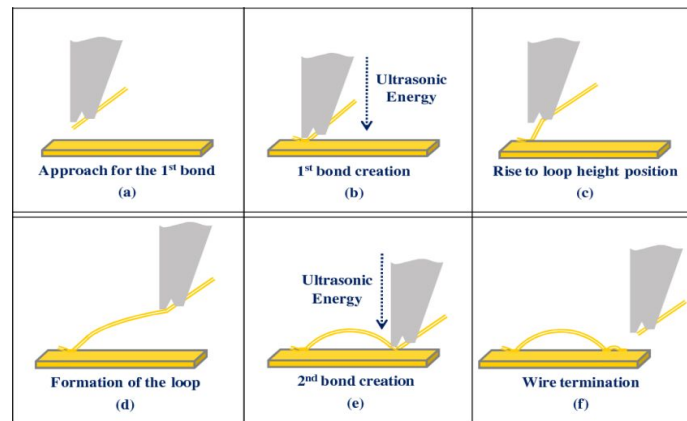
**Ball Bonding:** small ball formed and bonded.  
No directional constraints.



## Gold:

- High electrical conductivity;
- ball bonding;
- can be used with heater and NTD elements (high resistance).

**Wedge Bonding** – wire pressed and bonded.  
The wire must follow a straight path from the first bond.

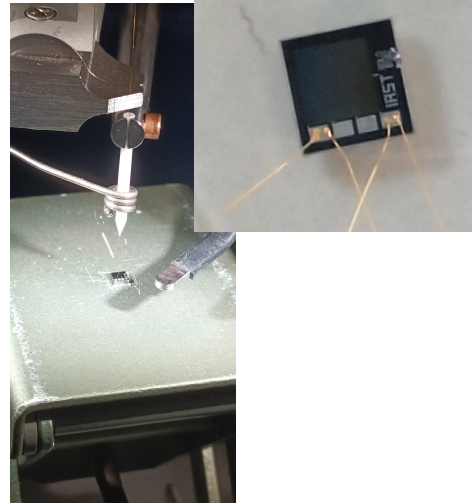
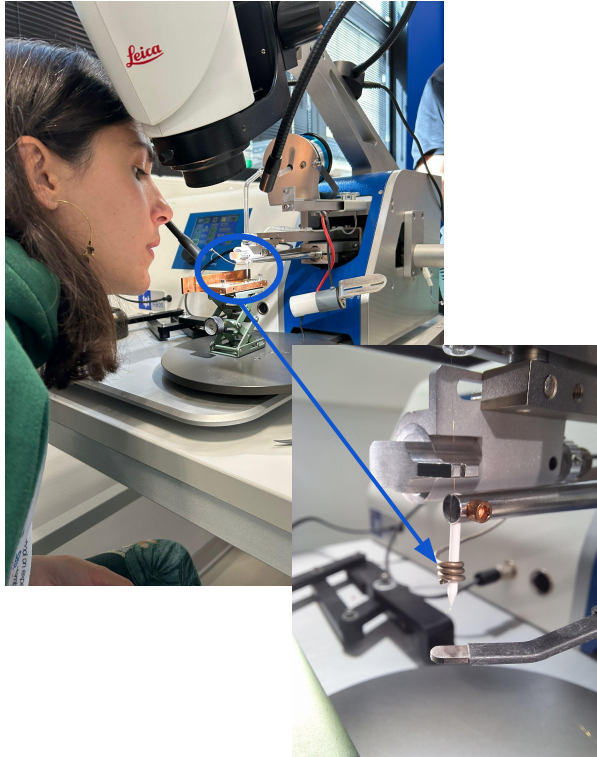


## Aluminum:

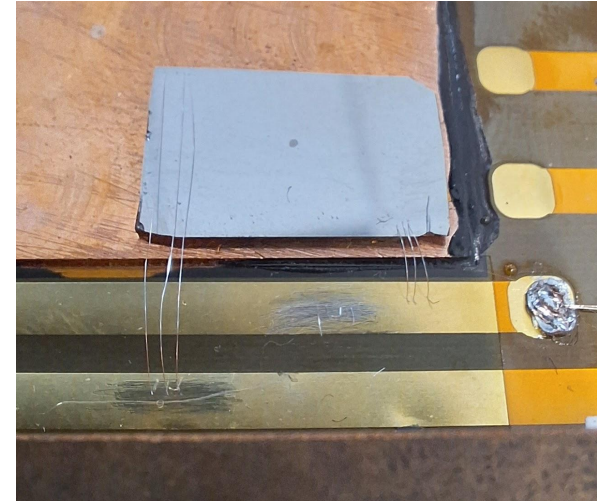
- Forming a ball is difficult because Al does not melt easily due to oxidation.
- Superconducting at low  $T^\circ \rightarrow$  used for TES (small stray resistance in bias circuit).

# Wire bonding

Gold bonding



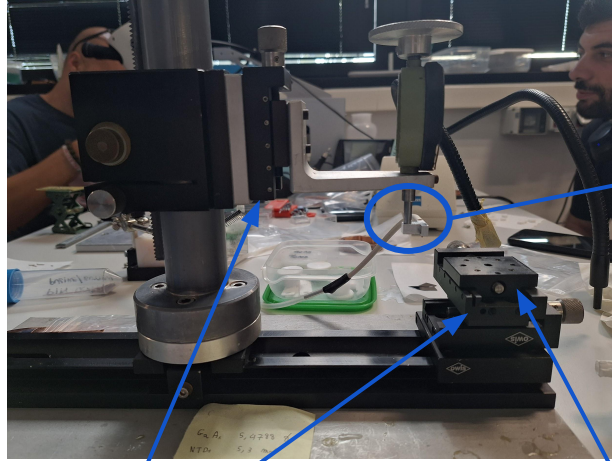
Aluminum bonding



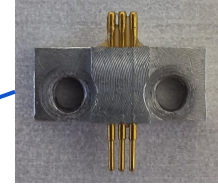
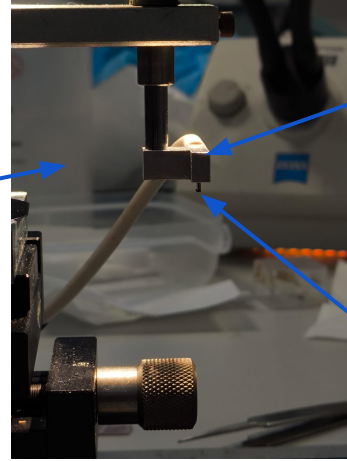
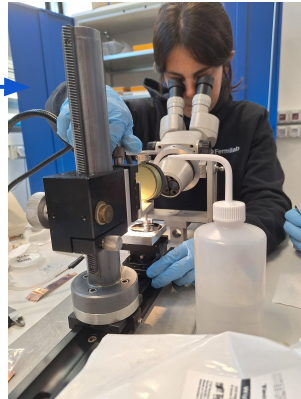
More wires → better connection to thermal bath



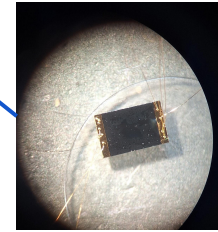
# Gluing setup



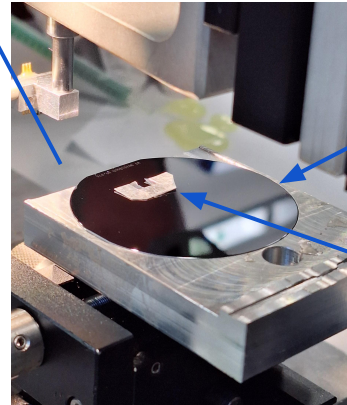
**5. xyz-stage** to align first the pins and later the NTD with the mask



**1. Pins** to apply the glue; dot shaped → compromise between phonon collection and thermal mismatch



**2. NTD** held by vacuum pump



**3. Crystal** (InAs or GaAs)

**4. Mask** for alignment + fix glue to defined thickness of  $25\mu\text{m}$

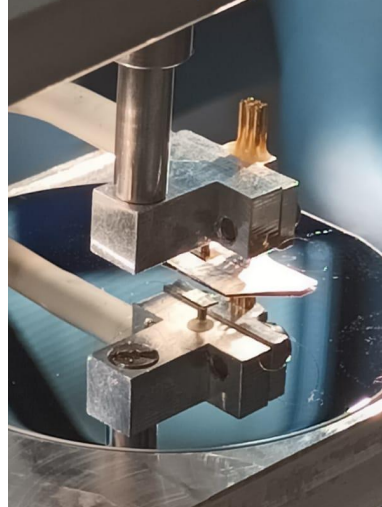
# Gluing procedure

**1.** Prepare the epoxy glue



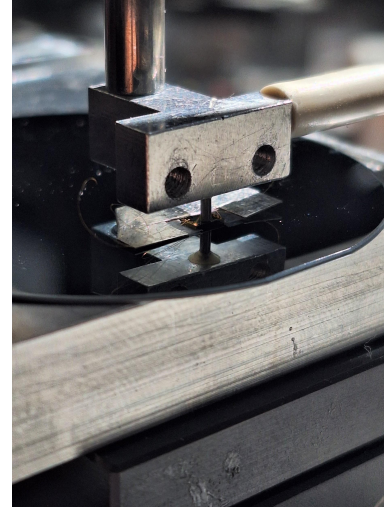
**2.** Apply some glue on the pins

**3.** Align the pins with the mask



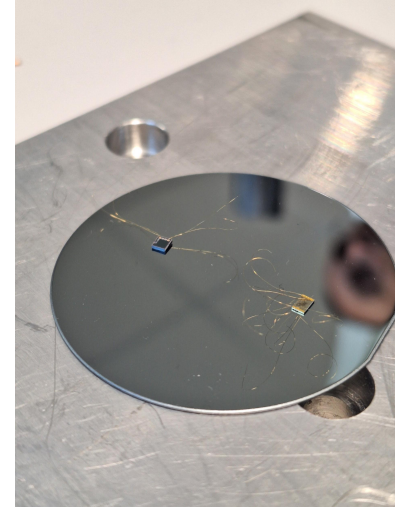
**4.** Apply the glue pattern on the wafer lowering the pins (springs prevent damage)

**5.** Unscrew the pins without touching the NTD



**6.** Align the NTD with the mask and press down

**7.** Wait for the glue to dry (~2h)



**8.** Remove the mask

# Final assembly

**1.** Clean copper frame with citric acid + deionized water to better couple to the bath (cryostat).

**2x2 pins for InAs**

**3x2 pins for GaAs**

**2.** Glue pins in frame with same glue as for NTDs; wrapped with tape for electrical insulation.

**3.** Tack crystal between PTFE stripes.

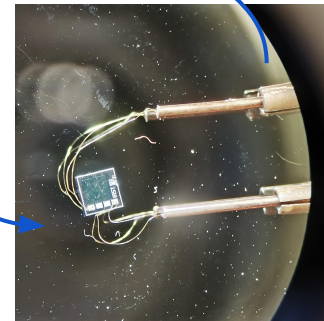
**4.** Mount crystal on copper frame.

**5.** Insert small copper pins and squeeze it tight.

Now it can be mounted in the cryostat.

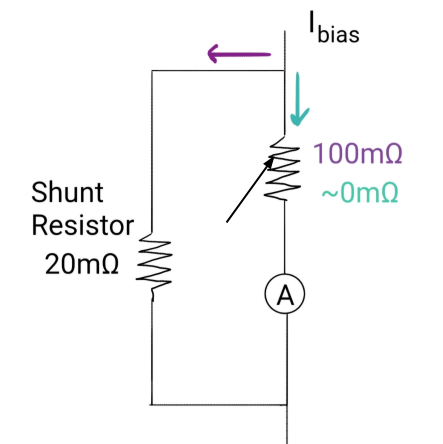


**7.** Check resistance of the devices and insulation against the frame.

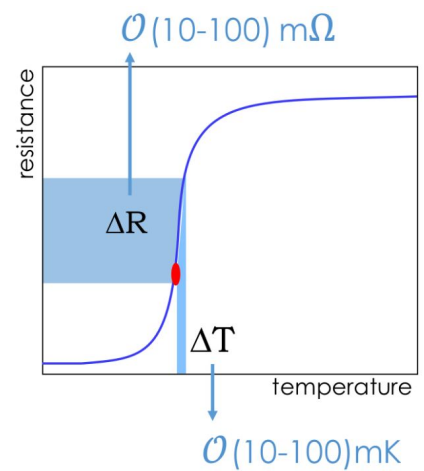
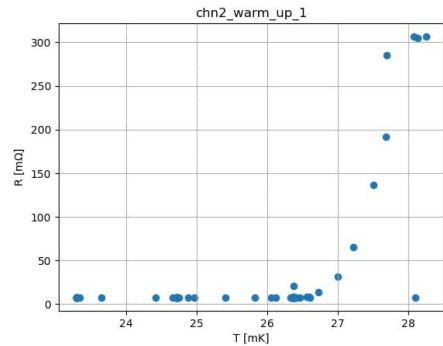


**6.** Insert the gold wires into the small pins and crimp them.

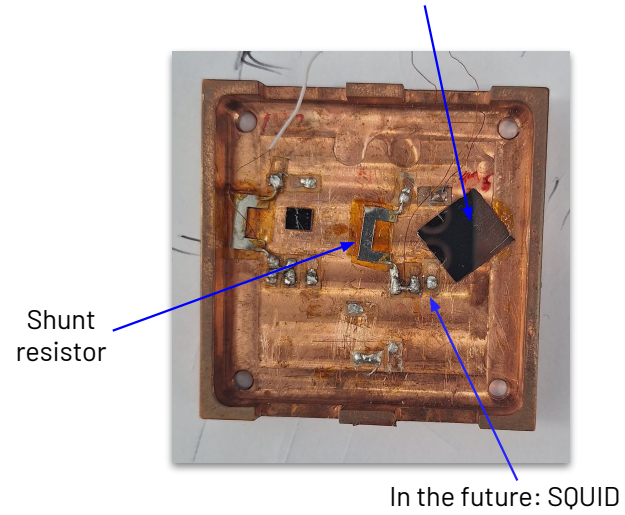
# Setup to measure the transition temperature $T_c$



The bias current flows through the shunt resistor and switch to the superconductive material when the superconductive state is reached.



Superconductive material: silicon with a thin layer of tungsten evaporated on top



Tungsten is used because it can tuned  $T_c$ , meaning that the transition can be adjusted according to the need of the detector operation.



# Thank you very much!

